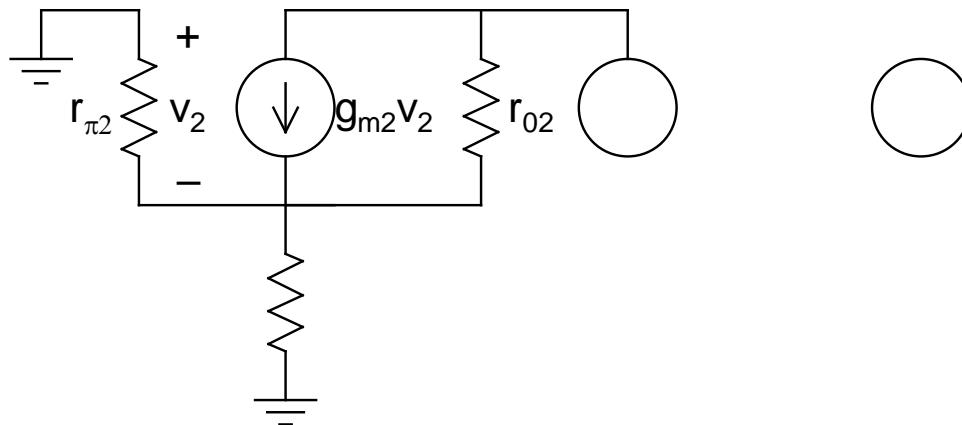


➤ *Calculation of R_0 :*

- *Golden Rule can't be used since emitter of Q_2 is not grounded (R_2 present there)*
- *Needs analysis*
⇒ *Leads to a module that is frequently encountered*
- *Base of Q_1 - Q_2 at a fixed DC potential ⇒ ac ground*



$$\begin{aligned} i_t &= g_{m2}v_2 + (v_t + v_2)/r_{02} \\ &= v_t/r_{02} + (g_{m2} + 1/r_{02})v_2 \quad v_t/r_{02} + g_{m2}v_2 \end{aligned}$$

$$v_2 = -i_t R_{\text{eff}}$$

$$\Rightarrow i_t = v_t/r_{02} - g_{m2}R_{\text{eff}}i_t$$

$$\Rightarrow R_0 = v_t/i_t = r_{02}(1 + g_{m2}R_{\text{eff}})$$

➤ This is a ***Golden Equation***, which would be *used frequently*

- *Carefully note the topology that produces this result*

➤ ***Exercise:*** *Reverse v_2 and show that the expression for R_0 remains invariant*

- If $r_{\pi 2} \gg R_2$, $R_0 = r_{02}(1 + g_m R_2)$
- If $R_2 \gg r_{\pi 2}$, $R_0 \approx \beta_2 r_{02}$ (since $\beta = g_m r_\pi \gg 1$)
- *Under the second condition, the circuit produces enormously large value of $R_0 \sim 10s$ of $M\Omega$ or greater*
 - *Almost approaches a constant current source!*
- *It's good to check the relative values of R_2 and $r_{\pi 2}$ before using either of the equations*
- *This circuit does not have any MOS counterpart for obvious reasons!*

- *Cascode Current Source*:
 - *The best and most widely used*
 - *Almost universal choice for biasing IC stages*
 - *Produces extremely high R_o*
 - *Original cascode needs higher values of $V_{0,min}$*
 - *Modified cascode gets rid of this problem and pushes $V_{0,min}$ down*
 - *The topology is basically two simple CMs stacked one upon the other*
 - *Both npn and NMOS implementations exist*

- *npn Cascode*:

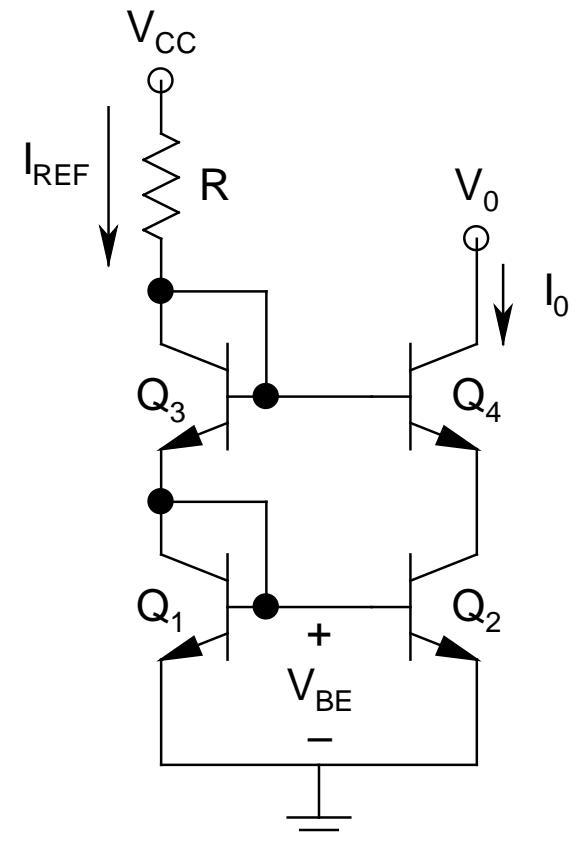
➤ All Qs are perfectly matched

➤ Neglecting I_B and V_A :

$$I_0 = I_{\text{REF}} = (V_{\text{CC}} - 2V_{\text{BE}})/R$$

➤ Show that if I_B can't be neglected, but all Qs have same β :

$$I_0 = \frac{I_{\text{REF}}}{1 + (4\beta + 2)/\beta^2}$$



➤ Thus, β immunity is not that pronounced

➤ *All Qs operate with the same V_{BE}*

$$\Rightarrow V_{B1} = V_{B2} = V_{BE}, V_{B3} = V_{B4} = 2V_{BE}$$

$$\Rightarrow V_{E4} = V_{C2} = V_{BE}$$

$$\Rightarrow V_{BE2} = V_{CE2}$$

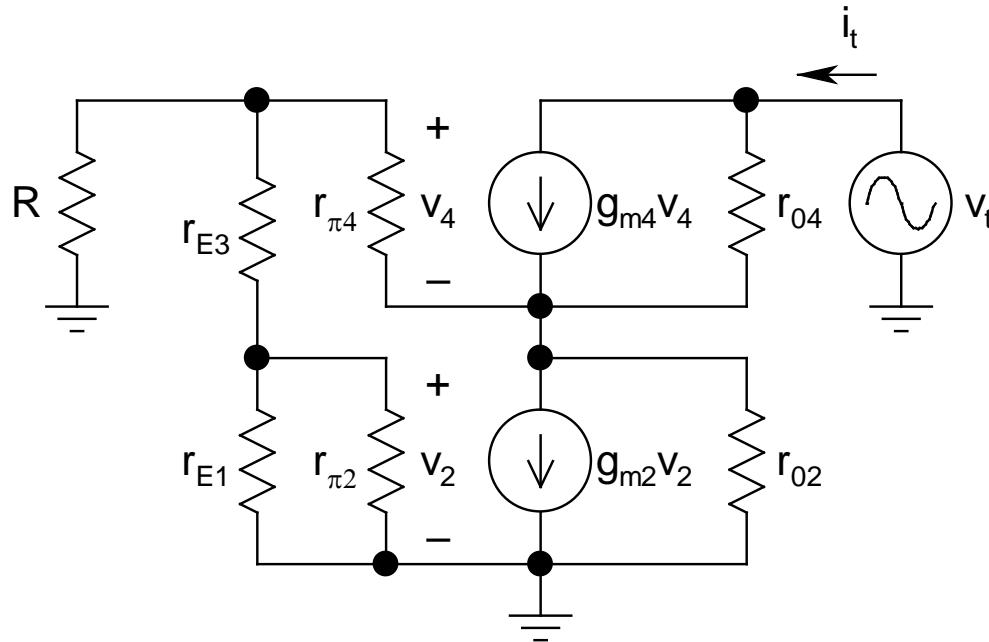
\Rightarrow *Q_2 can never saturate, but Q_4 can!*

$$\Rightarrow V_{0,\min} = V_{BE} + V_{CE4(SS)} = 0.7 + 0.2 = 0.9 \text{ V}$$

➤ *The output voltage swing is sacrificed quite a bit!*

➤ *However, the main advantage of this circuit is enormously large R_o*

➤ *Calculation of R_0 :*



- *Q_1 and Q_3 diode-connected $\Rightarrow r_{E1}$ and r_{E3}*

- Note that to a *first-order estimate*, bases of Q_1 - Q_2 and Q_3 - Q_4 can be considered to be at a *fixed DC potential*, and thus, *ac ground*

$$\Rightarrow v_2 = 0 \Rightarrow g_{m2}v_2 = 0$$

\Rightarrow Leads to the *simplified*

equivalent (looks

familiar?)

- *By inspection:*

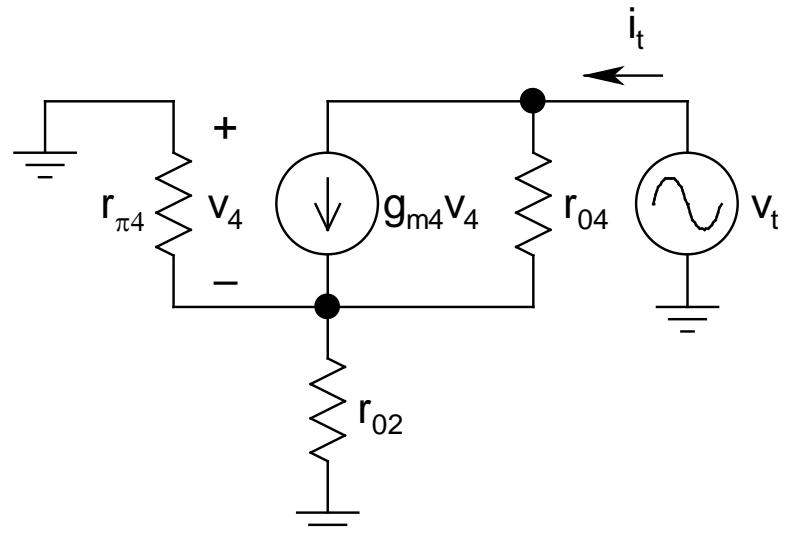
$$R_0 \approx r_{o4}(1 + g_{m4}r_{\pi4})$$

$$\approx \beta_4 r_{o4}$$

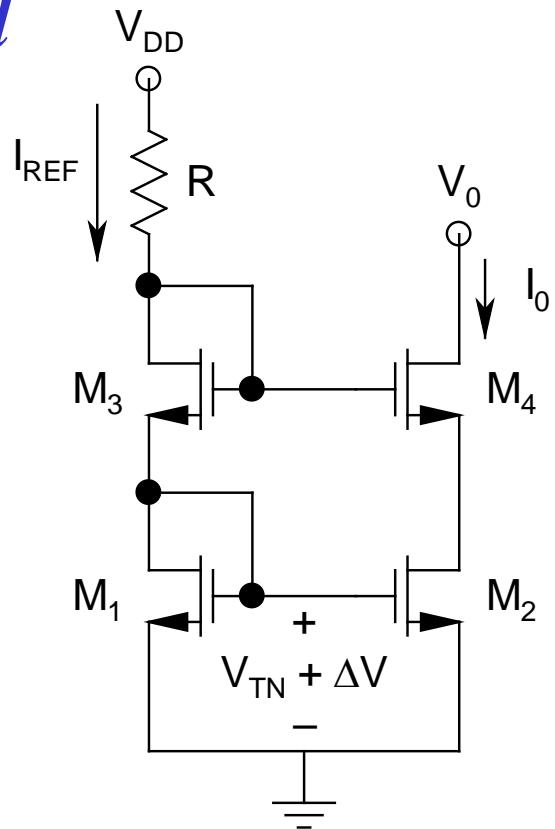
(assuming $r_{o2} \gg r_{\pi4}$)

- *Actual analysis gives:*

$$R_0 = \beta_4 r_{o4}/2 \text{ (large error!)}$$



- **NMOS Cascode:**
 - All Ms perfectly matched
 - All bodies connected to ground
 - *M_1 - M_2 does not have body effect, but M_3 - M_4 does!*
 - *Makes hand analysis quite tedious*
 - ⇒ *Neglect body effect*
 - All Ms operate with same V_{GS}
 - Define $\Delta V = V_{GS} - V_{TN} = V_{GT}$
 - $\Delta V = \text{Gate Overdrive}$



➤ ***The reference current:***

$$I_{REF} = \frac{V_{DD} - 2V_{GS}}{R} = \frac{k_N}{2} V_{GT}^2 \quad (\text{neglecting } \lambda)$$

➤ ***V_{GS} and I_{REF} can be found*** $\Rightarrow I_0 = I_{REF}$

➤ $V_{G1} = V_{G2} = V_{GS} = V_{TN} + \Delta V$

➤ $V_{G3} = V_{G4} = 2V_{GS} = 2(V_{TN} + \Delta V)$

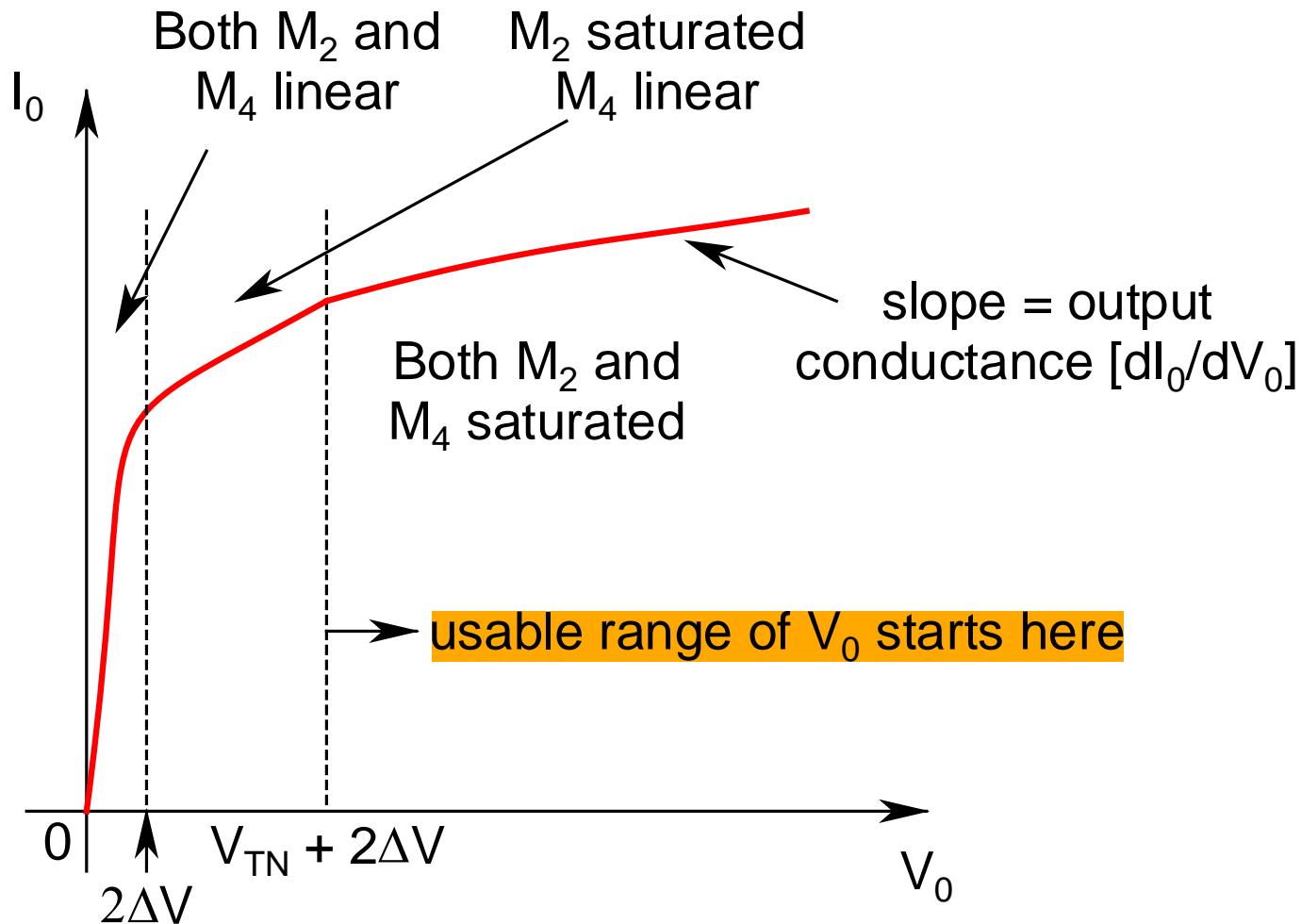
➤ $V_{S4} = V_{D2} = V_{TN} + \Delta V$

$$\Rightarrow V_{GS2} = V_{DS2}$$

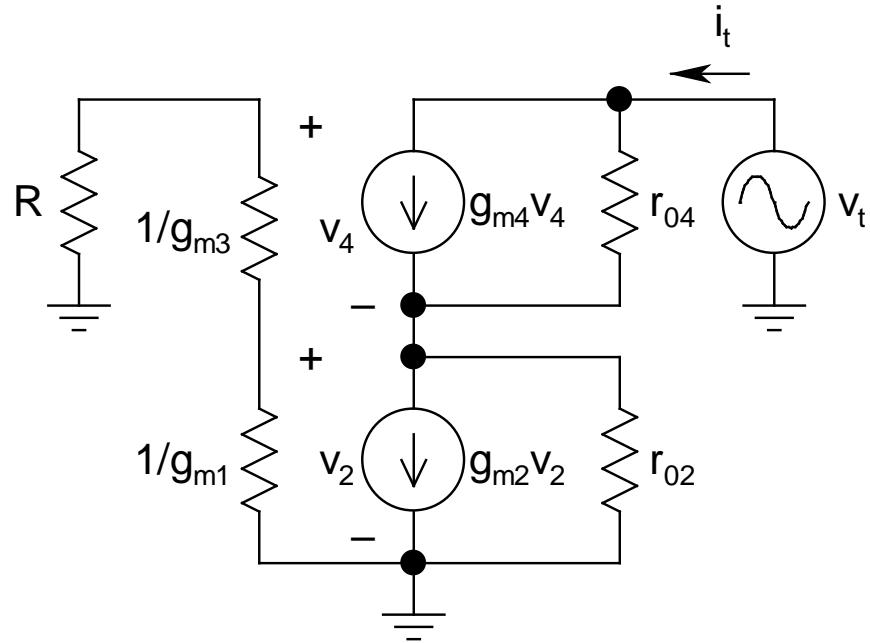
\Rightarrow ***M_2 can never enter linear region***

$$\Rightarrow V_{0,\min} = V_{DS2} + V_{DS4} = V_{TN} + 2\Delta V$$

- *This can be quite significant, since V_{TN} is added to ΔV*
 - Assuming $\Delta V \sim 0.1$ V and $V_{TN} \sim 0.7$ V, $V_{0,min} \sim 0.9$ V, which is very large
 - *This is one of the drawbacks of this simple cascode circuit (modified cascode doesn't have this problem)*
- *If V_0 drops below $(V_{TN} + 2\Delta V)$, first M_4 enters linear region, and circuit performance starts to get affected*
- *For further drop in V_0 , M_2 also enters linear region, and the current mirror collapses!*



➤ *Calculation of R_0 :*



Exact Equivalent

- *M_1 and M_3 diode-connected* $\Rightarrow 1/g_{m1}$ and $1/g_{m3}$

- *The left part of the circuit has no source*

$$\Rightarrow v_2 = 0 \Rightarrow g_{m2}v_2 = 0$$

\Rightarrow *Leads to the simplified equivalent* (now should look very familiar!)

- *By inspection:*

$$R_0 \approx r_{o4}(1 + g_{m4}r_{o2})$$

$$\approx g_{m4}r_{o2}r_{o4}$$

- *Can be huge!*

